

Dr. Manish Kumar Mohanta

+918763522933 | mkmohanta@iitbbs.ac.in | IIT-Bhubaneswar, Odisha, India
<https://manishmohanta.wordpress.com>

COMPUTATIONAL MATERIALS SCIENTIST

Innovative computational materials scientist specializing in quantum materials and density functional theory. Recognized among the top 2% of scientists globally in Applied Physics by Stanford University. Expertise in electronic structure calculations, spintronics, valleytronics, and energy materials. Dedicated to advancing next-generation electronic and energy harvesting devices through advanced analytical modeling and density functional theory.

KEY EXPERTISE & CORE ACCOMPLISHMENTS

- Condensed Matter Physics
 - Computational Materials Physics
 - Density Functional Theory
 - Quantum Materials
 - Analytical Modeling
 - Spintronics & Valleytronics
 - Energy Materials & Devices
 - Nanocluster & Catalysis
- Ranked among the top **2%** of scientists globally in Applied Physics by Stanford University in 2023, 2024 & 2025
 - Published over **36** peer-reviewed articles, including Physical Review B, ACS Applied Materials & Interfaces.

PROFESSIONAL EXPERIENCE

- | | |
|--|---------------------------|
| Ramanujan Faculty
<i>Department of Physics</i>
<i>Indian Institute of Technology–Bhubaneswar, Odisha, India</i> | November 2025-Present |
| Postdoctoral Research Fellow
<i>Department of Physics</i>
<i>Virginia Commonwealth University – Richmond, USA</i> | October 2022-October 2025 |
| Research Associate-1
<i>Institute of Nano Science and Technology – Mohali, India</i> | April 2022- October 2022 |

EDUCATION

Doctor of Philosophy in Physics

01/2017 – 06/2022

Indian Institute of Science Education and Research (IISER) – Mohali, India

Doctoral Thesis: “**Ab initio Insights into Applied 2D Materials for Energy Harvesting and Next-generation Devices**”

Adviser: Prof. Abir De Sarkar, Institute of Nano Science and Technology – Mohali, India

Master of Science in Applied Physics

06/2014 – 05/2016

Indian Institute of Technology (Indian School of Mines) – Dhanbad, India

CGPA: 8.9/10

Bachelor of Science in Physics

06/2011 – 05/2014

B.J.B Autonomous College (under Utkal University) – Bhubaneswar, India

Mark: 78.8%

Intermediate

06/2009 – 05/2011

Royal College of Science and Technology – Bhubaneswar, India

Mark: 86.83%

SKILLS & ADDITIONAL INFORMATION

Computational Skills

- | | |
|--------------------|------------|
| • VASP | • Phonopy |
| • Quantum Espresso | • Phono3py |
| • Gaussian | • Python |
| • ASE | • Matlab |

Awards & Honors

- | | |
|-----------|---|
| 2025 | Ramanujan Faculty Fellowship – IIT-Bhubaneswar |
| 2025 | World's Top 2% Scientist Rank: 5414 – Applied Physics, Stanford University |
| | American Physical Society (APS) – Division of Materials Physics (DMP) Post-Doctoral |
| 2024 | Travel Award |
| 2024 | World's Top 2% Scientist Rank: 3904 – Applied Physics, Stanford University |
| 2023 | World's Top 2% Scientist Rank: 4527 – Applied Physics, Stanford University |
| 2022 | Karnataka DST Nano Science Fellowship |
| 2017–2022 | PhD fellowship/stipend sponsored by the Council of Scientific & Industrial Research (CSIR) under the Ministry of Science & Technology, Govt. of India |
| | <ul style="list-style-type: none">• CSIR- JRF, AIR 94 - December |
| 2016 | <ul style="list-style-type: none">• CSIR- JRF, AIR 221 – June• Joint Entrance Screening Test (JEST), AIR 239• Graduate Aptitude Test in Engineering (GATE), AIR 1603 |
| 2011–2016 | INSPIRE – Scholarship for Higher Education sponsored by the Department of Science & Technology, Govt. of India |

RESEARCH PUBLICATIONS

Google Scholar

<https://scholar.google.com/citations?user=2QwvQDoAAAAAJ&hl=en&oi=ao>

ORCID

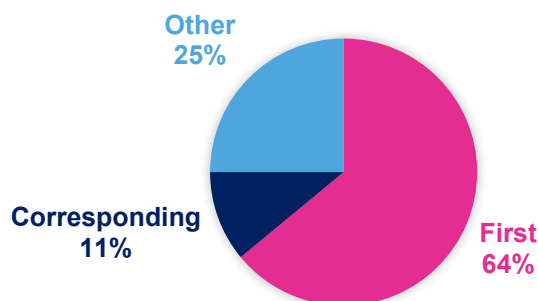
<https://orcid.org/0000-0002-5476-8336>

Publications Summary

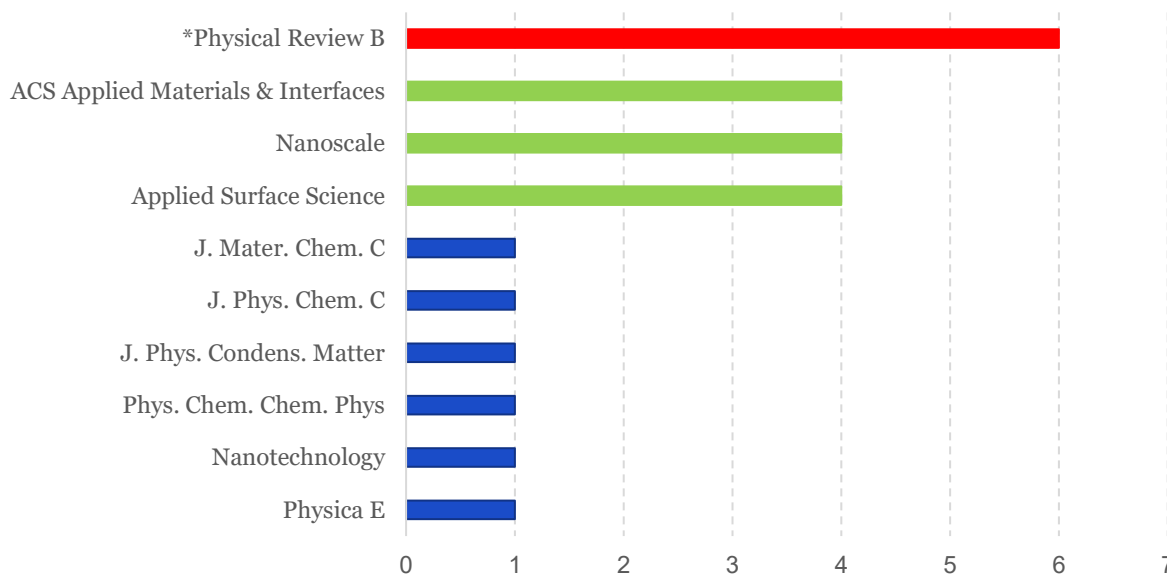
- ✓ No. of citations = 1500+ ([Google Scholar](#)), h – index=**23**, i10 – index=25
 - ✓ A Total of **36** papers with **24** as the **First Author**
-

Author Position

Total number of peer-reviewed publications: **36**



First & Corresponding Author Publications: **24**



PEER-REVIEWED PUBLICATIONS

2025	IF
36 M.K. Mohanta , P. Jena, Anomalous spin texture representation in quantum materials: Insights from density functional theory and analytical models, Phys. Rev. B 111 (2025) 045140. https://doi.org/10.1103/PhysRevB.111.045140 .	3.2
35 M.K. Mohanta , P. Jena, Activation and electrochemical reduction of carbon dioxide by transition metal atom-doped copper clusters, Nanoscale 17 (2025) 8505–8514. https://doi.org/10.1039/D4NR03795B . [Cover-Image]	5.8
34 R.C. Sahoo, M.K. Mohanta , D. Tamudia, P. Jena, H.S.S.R. Matte, Nickel Silicate Hydroxides/Expanded Graphite as a Stable and Fast-charging Anode for the Next-generation Li-ion Batteries, ACS Appl. Mater. Interfaces 17 (2025) 14157–14167. https://doi.org/10.1021/acsami.4c17955 .	8.5
33 S. Vishwanathan, M.K. Mohanta , P. Jena, H.S.S.R. Matte, Experimental and theoretical insights on interface engineered FeS/rGO as anode for fast-charging lithium- and sodium-ion batteries, Small 21 (2025) 2410482. https://doi.org/10.1002/sml.202410482 .	13
32 M.K. Alam, M.K. Mohanta , D. White, J. Baker, L.S. Graves, P. Jena, I.U. Arachchige, Facile synthesis of cubic Ni _{1-x} Cr _x nanoalloys and their composition-dependent electrocatalytic activity for the hydrogen evolution reaction, Nanotechnology 36 (2025) 225401. https://doi.org/10.1088/1361-6528/add26f .	2.9
2024	
31 M.K. Mohanta , P. Jena, MgTe (110) semiconductor for a magnetic-element-free nonballistic spin-field-effect transistor, Phys. Rev. B 109 (2024) 085415. https://doi.org/10.1103/PhysRevB.109.085415 .	3.2
30 R.C. Sahoo, P. Sahoo, M.K. Mohanta , P. Jena, H.S.S.R. Matte, Solution processing of spinel nickel cobaltite: Exfoliation mechanism, dispersion stability, and applications, Inorg. Chem. 63 (2024) 7838–7847. https://doi.org/10.1021/acs.inorgchem.4c00430 .	4.3
29 M.K. Mohanta , P. Jena, Magnetism of Otherwise Nonmagnetic Elements: From Clusters to Monolayers, J. Phys. Chem. C 128 (2024) 12286–12295. https://doi.org/10.1021/acs.jpcc.4c03592 .	3.3
28 M.K. Mohanta , P. Jena, In ₂ Si ₂ S ₃ X ₃ (X = S, Se, Te) Janus monolayers: from magnetic element-free spin-Hall transistor to sustainable energy generation, J. Mater. Chem. C 12 (2024) 1888–1896. https://doi.org/10.1039/D3TC03805J .	5.7
2023	
27 M.K. Mohanta , P. Jena, Symmetry-driven persistent spin texture for the two-dimensional nonsymmorphic CdTe and ZnTe crystal structures, Phys. Rev. B 108 (2023) 085432. https://doi.org/10.1103/PhysRevB.108.085432 .	3.2
26 M.K. Mohanta , F. IS, A. De Sarkar, Valley Hall effect in graphene-like SnX (X=Si, Ge) buckled monolayers with high charge carrier mobility and low lattice thermal conductivity, Phys. Rev. B 107 (2023) 035429. https://doi.org/10.1103/PhysRevB.107.035429 .	3.2
25 F. IS, M.K. Mohanta , A.D. Sarkar, Insights into selected 2D piezo Rashba semiconductors for self-powered flexible piezo spintronics: material to contact properties, J. Phys. Condens. Matter 35 (2023) 253001. https://doi.org/10.1088/1361-648X/acc70f .	2.3

2022

- 24 **M.K. Mohanta**, H. Seksaria, A.D. Sarkar, Insights into CrS₂ monolayer and n-CrS₂/p-HfN₂ interface for low-power digital and analog nanoelectronics, **Applied Surface Science**. 579 (2022) 152211. <https://doi.org/10.1016/j.apsusc.2021.152211>. 6.3

2021

- 23 **M.K. Mohanta**, A. Arora, A. De Sarkar, Effective modulation of ohmic contact and carrier concentration in a graphene-MgX (X=S, Se) van der Waals heterojunction with tunable band-gap opening via strain and electric field, **Phys. Rev. B**. 104 (2021) 165421. <https://doi.org/10.1103/PhysRevB.104.165421>. 3.2
- 22 **M.K. Mohanta**, F. IS, A. Kishore, A. De Sarkar, Spin-Current Modulation in Hexagonal Buckled ZnTe and CdTe Monolayers for Self-Powered Flexible-Piezo-Spintronic Devices, **ACS Appl. Mater. Interfaces**. 13 (2021) 40872–40879. <https://doi.org/10.1021/acsami.1c09267>. 8.3
- 21 **M.K. Mohanta**, A. Arora, A. De Sarkar, Conflux of tunable Rashba effect and piezoelectricity in flexible magnesium monochalcogenide monolayers for next-generation spintronic devices, **Nanoscale**. 13 (2021) 8210–8223. <https://doi.org/10.1039/D1NR00149C>. 5.8
- 20 **M.K. Mohanta**, A.D. Sarkar, 2D HfN₂/graphene interface based Schottky device: Unmatched controllability in electrical contacts and carrier concentration via electrostatic gating and out-of-plane strain, **Applied Surface Science**. 540 (2021) 148389. <https://doi.org/10.1016/j.apsusc.2020.148389>. 6.3
- 19 **M.K. Mohanta**, A. Rawat, A.D. Sarkar, Atomistic manipulation of interfacial properties in HfN₂/MoTe₂ van der Waals heterostructure via strain and electric field for next generation multifunctional nanodevice and energy conversion, **Applied Surface Science**. 568 (2021) 150928. <https://doi.org/10.1016/j.apsusc.2021.150928>. 6.3

2020

- 18 **M.K. Mohanta**, A. De Sarkar, Coupled spin and valley polarization in monolayer HfN₂ and valley-contrasting physics at the HfN₂-WSe₂ interface, **Phys. Rev. B**. 102 (2020) 125414. <https://doi.org/10.1103/PhysRevB.102.125414>. 3.2
- 17 **M.K. Mohanta**, A. Rawat, N. Jena, Dimple, R. Ahammed, A. De Sarkar, Interfacing Boron Monophosphide with Molybdenum Disulfide for an Ultrahigh Performance in Thermoelectrics, Two-Dimensional Excitonic Solar Cells, and Nanopiezotronics, **ACS Appl. Mater. Interfaces**. 12 (2020) 3114–3126. <https://doi.org/10.1021/acsami.9b16866>. 8.3
- 16 **M.K. Mohanta**, A.D. Sarkar, Tweaking the Physics of Interfaces between Monolayers of Buckled Cadmium Sulfide for a Superhigh Piezoelectricity, Excitonic Solar Cell Efficiency, and Thermoelectricity, **ACS Appl. Mater. Interfaces**. 12 (2020) 18123–18137. <https://doi.org/10.1021/acsami.0c00864>. 8.3
- 15 **M.K. Mohanta**, A. De Sarkar, Interfacial hybridization of Janus MoSSe and BX (X = P, As) monolayers for ultrathin excitonic solar cells, nanopiezotronics and low-power memory devices, **Nanoscale**. 12 (2020) 22645–22657. <https://doi.org/10.1039/D0NR07000A>. 5.8
- 14 **M.K. Mohanta**, I.S. Fathima, A. De Sarkar, Exceptional mechano-electronic properties in the HfN₂ monolayer: a promising candidate in low-power flexible electronics, memory devices and photocatalysis, **Phys. Chem. Chem. Phys.** 22 (2020) 21275–21287. 2.9

<https://doi.org/10.1039/DoCP02999H>.

- 13 **M.K. Mohanta**, A.D. Sarkar, Giant tunability in electrical contacts and doping via inconsiderable normal electric field strength or gating for a high-performance in ultrathin field effect transistors based on 2D BX/graphene (X = P, As) van der Waals heterobilayer, **Applied Surface Science**. 526 (2020) 146749. <https://doi.org/10.1016/j.apsusc.2020.146749>. 6.3
- 12 **M.K. Mohanta**, A. Kishore, A. De Sarkar, Two-dimensional ultrathin van der Waals heterostructures of indium selenide and boron monophosphide for superfast nanoelectronics, excitonic solar cells, and digital data storage devices, **Nanotechnology**. 31 (2020) 495208. <https://doi.org/10.1088/1361-6528/abaf20>. 2.9
- 11 **M.K. Mohanta**, A. Rawat, N. Jena, R. Ahammed, A.D. Sarkar, Superhigh flexibility and out-of-plane piezoelectricity together with strong anharmonic phonon scattering induced extremely low lattice thermal conductivity in hexagonal buckled CdX (X = S, Se) monolayers, **Journal of Physics: Condensed Matter**. 32 (2020) 355301. <https://doi.org/10.1088/1361-648x/ab8d73>. 2.3
- 10 **M.K. Mohanta**, Dimple, A. Rawat, N. Jena, R. Ahammed, A.D. Sarkar, Ultra-low thermal conductivity and super-slow hot-carrier thermalization induced by a huge phononic gap in multifunctional nanoscale boron pnictides, **Physica E: Low-Dimensional Systems and Nanostructures**. 124 (2020) 114222. <https://doi.org/10.1016/j.physe.2020.114222>. 2.9
- 9 A. Medda, A. Dutta, D. Bain, **M.K. Mohanta**, A. De Sarkar, A. Patra, Electronic Structure Modulation of 2D Colloidal CdSe Nanoplatelets by Au₂₅ Clusters for High-Performance Photodetectors, **J. Phys. Chem. C**. 124 (2020) 19793–19801. <https://doi.org/10.1021/acs.jpcc.0c04774>. 3.3
- 8 Dimple, **M.K. Mohanta**, A. Rawat, N. Jena, R. Ahammed, A.D. Sarkar, Ultra-low lattice thermal conductivity and giant phonon–electric field coupling in hafnium dichalcogenide monolayers, **Journal of Physics: Condensed Matter**. 32 (2020) 315301. <https://doi.org/10.1088/1361-648x/ab7e5f>. 2.3
- 7 R. Ahammed, A. Rawat, N. Jena, Dimple, **M.K. Mohanta**, A.D. Sarkar, ZrS₃/MS₂ and ZrS₃/MXY (MMo, W; X, YS, Se, Te; X ≠ Y) type-II van der Waals hetero-bilayers: Prospective candidates in 2D excitonic solar cells, **Applied Surface Science**. 499 (2020) 143894. <https://doi.org/10.1016/j.apsusc.2019.143894>. 6.3
- 6 R. Ahammed, N. Jena, A. Rawat, **M.K. Mohanta**, Dimple, A. De Sarkar, Ultrahigh Out-of-Plane Piezoelectricity Meets Giant Rashba Effect in 2D Janus Monolayers and Bilayers of Group IV Transition-Metal Trichalcogenides, **J. Phys. Chem. C**. 124 (2020) 21250–21260. <https://doi.org/10.1021/acs.jpcc.0c05134>. 3.3
- 5 A. Rawat, **M.K. Mohanta**, N. Jena, Dimple, R. Ahammed, A. De Sarkar, Nanoscale Interfaces of Janus Monolayers of Transition Metal Dichalcogenides for 2D Photovoltaic and Piezoelectric Applications, **J. Phys. Chem. C**. 124 (2020) 10385–10397. <https://doi.org/10.1021/acs.jpcc.0c02199>. 3.3

2019

- 4 **M.K. Mohanta**, A. Rawat, Dimple, N. Jena, R. Ahammed, A. De Sarkar, Superhigh out-of-plane piezoelectricity, low thermal conductivity and photocatalytic abilities in ultrathin 2D van der Waals heterostructures of boron monophosphide and gallium nitride, **Nanoscale**. 11 (2019) 21880–21890. <https://doi.org/10.1039/C9NR07586K>. [Editor's Choice] 5.8

- 3 N. Jena, Dimple, R. Ahammed, A. Rawat, **M.K. Mohanta**, A. De Sarkar, Valley drift and valley current modulation in strained monolayer MoS₂, **Phys. Rev. B.** 100 (2019) 165413. <https://doi.org/10.1103/PhysRevB.100.165413>. 3.2
- 2 A. Rawat, R. Ahammed, Dimple, N. Jena, **M.K. Mohanta**, A. De Sarkar, Solar Energy Harvesting in Type II van der Waals Heterostructures of Semiconducting Group III Monochalcogenide Monolayers, **J. Phys. Chem. C.** 123 (2019) 12666–12675. <https://doi.org/10.1021/acs.jpcc.9b03359>. 3.3

2018

- 1 Dimple, N. Jena, A. Rawat, R. Ahammed, **M.K. Mohanta**, A.D. Sarkar, Emergence of high piezoelectricity along with robust electron mobility in Janus structures in semiconducting Group IVB dichalcogenide monolayers, **J. Mater. Chem. A.** 6 (2018) 24885–24898. <https://doi.org/10.1039/C8TA08781D>. 10.7

CONFERENCE PRESENTATIONS

March 2024 – American Physical Society (APS), Minnesota

1. **Title:** Symmetry-Driven Persistent Spin Texture Towards Ferromagnet-free Non-Ballistic Spintronics
Authors: **Manish Kumar Mohanta**, Puru Jena
2. **Title:** From clusters to crystals: Magnetism of otherwise nonmagnetic elements in two-dimension
Authors: **Manish Kumar Mohanta**, Puru Jena

PROFESSIONAL SERVICES

Peer Reviewer

- | | |
|---|------------------------------------|
| • Physical Review B | • Materials Advances |
| • Nano Letters | • 2D Materials |
| • Journal of Materials Chemistry A | • Journal of Materials Chemistry C |
| • Journal of Physical Chemistry Letters | • ACS Applied Energy Materials |
| • Nanoscale | • ACS Omega |
| • Phys. Chem. Chem. Phys | • Surfaces and Interfaces |
| • Scientific Reports | • Materials Research Express |

REFERENCES

- 1 **Prof. Puru Jena [Postdoc Supervisor]**
Distinguished Professor, Department of Physics,
Virginia Commonwealth University, Richmond, USA
Email: pjena@vcu.edu
- 2 **Prof. Abir De Sarkar [PhD Supervisor]**
Professor, Institute of Nano Science and Technology, Mohali, India
Email: abir@inst.ac.in
- 3 **Prof. HSS Ramakrishna Matte [Experimental Collaborator]**
Scientist-D, Centre for Nano and Soft Matter Sciences, Bengaluru, India
Email: matte@cens.res.in
- 4 **Prof. Indika U Arachchige [Experimental Collaborator]**
Professor, Department of Chemistry,
Virginia Commonwealth University, Richmond, USA
Email: iuarachchige@vcu.edu